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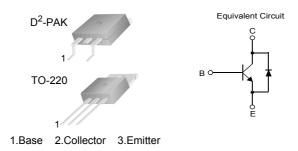
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# KSC5338D/KSC5338DW NPN Triple Diffused Planar Silicon Transistor

## Features

- High Voltage Power Switch Switching Application
- Wide Safe Operating Area
- Built-in Free-Wheeling Diode
- Suitable for Electronic Ballast Application
- Small Variance in Storage Time
- Two Package Choices : TO-220 or D<sup>2</sup>-PAK



### Absolute Maximum Ratings T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	1000	V
V <sub>CEO</sub>	Collector-Emitter Voltage	450	V
V <sub>EBO</sub>	Emitter-Base Voltage	12	V
Ι <sub>C</sub>	Collector Current (DC)	5	А
I <sub>CP</sub>	*Collector Current (Pulse)	10	А
I <sub>B</sub> Base Current (DC)		2	А
I <sub>BP</sub>	*Base Current (Pulse)	4	А
P <sub>C</sub>	Power Dissipation (T <sub>C</sub> =25°C)	75	W
ТJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 to 150	°C

\* Pulse Test : Pulse Width = 5ms, Duty Cycle  $\leq$  10%

## **Thermal Characteristics**

Symbol	Parameter		Rating	Units
R <sub>θjc</sub>	Thermal Resistance	Junction to Case	1.65	°C/W
R <sub>θja</sub>		Junction to Ambient	62.5	°C/W
TL	Maximum Lead Temperature for Soldering		270	°C

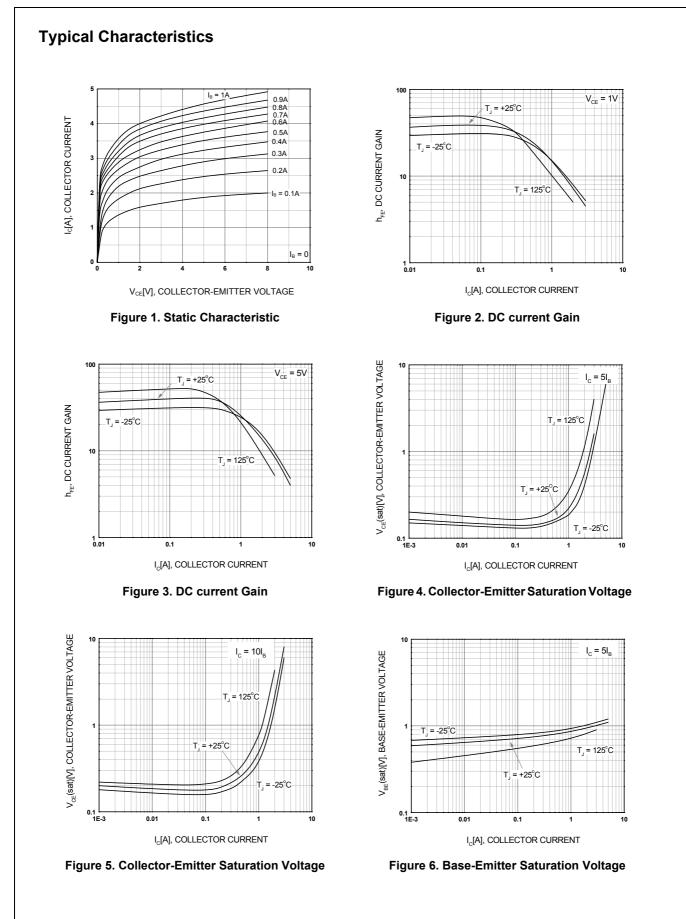
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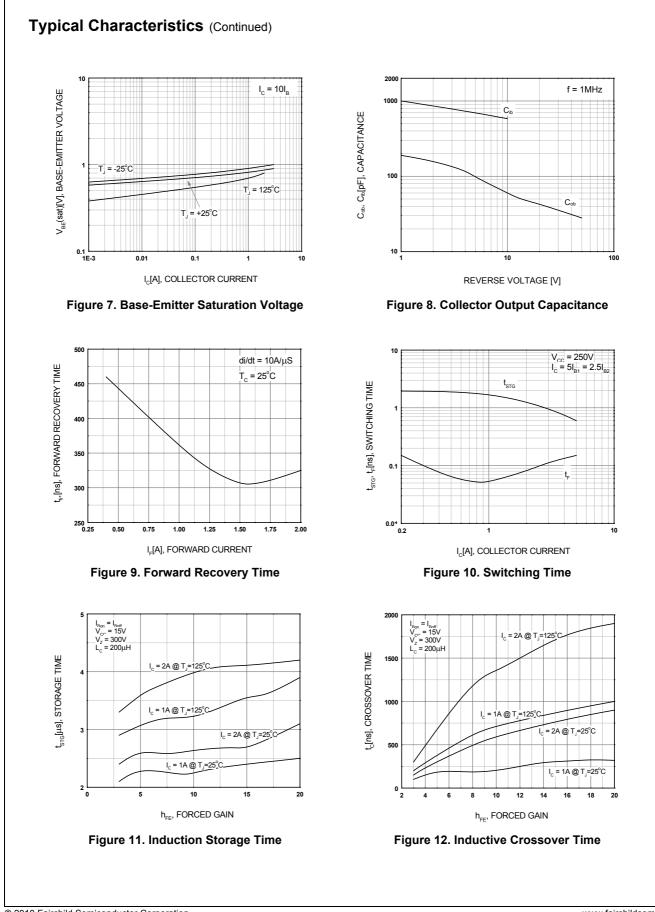
May 2010

Symbol	Parameter	Test Condition		Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =1mA, I <sub>E</sub> =0		1000			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage			450			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =1mA, I <sub>C</sub> =0		12			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =800V, I <sub>E</sub> =0				10	μA
I <sub>CES</sub>	Collector Cut-off Current	V <sub>CES</sub> =1000V, I <sub>EB</sub> =0	T <sub>a</sub> =25°C			100	μA
010						500	μA
I <sub>CEO</sub>	Collector Cut-off Current	V <sub>CF</sub> =450V, I <sub>B</sub> =0	T <sub>a</sub> =25°C			100	μA
020						500	μA
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> =10V, I <sub>C</sub> =0	u			10	μA
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> =1V, I <sub>C</sub> =0.8A	T <sub>a</sub> =25°C	15	25		
				10	14		
		V <sub>CE</sub> =1V, I <sub>C</sub> =2A	T <sub>a</sub> =25°C	6	9		
		02 0	T <sub>a</sub> =125°C	4	6		
		V <sub>CE</sub> =2.5V, I <sub>C</sub> =1A	T <sub>a</sub> =25°C	18	25		
			T <sub>a</sub> =125°C	14	18		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =0.8A, I <sub>B</sub> =0.08A	T <sub>a</sub> =25°C		0.35	0.5	V
UL V		0 1	T <sub>a</sub> =125°C		0.55	0.75	V
		I <sub>C</sub> =2A, I <sub>B</sub> =0.4A	T <sub>a</sub> =25°C		0.47	0.75	V
		0 1 0	T <sub>a</sub> =125°C		0.9	1.1	V
		I <sub>C</sub> =0.8A, I <sub>B</sub> =0.04A			0.9	1.5	V
		0 / 0			1.8	2.5	V
		I <sub>C</sub> =1A, I <sub>B</sub> =0.2A	T <sub>a</sub> =25°C		0.22	0.5	V
			T <sub>a</sub> =125°C		0.3	0.6	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> =0.8A, I <sub>B</sub> =0.08A	T <sub>a</sub> =25°C		0.8	1.0	V
DE( )					0.65	0.9	V
		I <sub>C</sub> =2A, I <sub>B</sub> =0.4A	T <sub>a</sub> =25°C		0.9	1.0	V
					0.8	0.9	V
C <sub>ib</sub>	Input Capacitance	V <sub>EB</sub> =10V, I <sub>C</sub> =0.5A,	~		550	750	pF
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1			60	100	pF
f <sub>T</sub>	Current Gain Bandwidth Product	I <sub>C</sub> =0.5A,V <sub>CE</sub> =10V			11		MHz
V <sub>F</sub>	Diode Forward Voltage	I <sub>F</sub> =1A, I <sub>C</sub> =1mA,	T <sub>a</sub> =25°C		0.86	1.3	V
		I <sub>E</sub> =0			0.79		V
		I <sub>F</sub> =2A	T <sub>a</sub> =25°C		0.95	1.5	V
			T <sub>a</sub> =125°C		0.88		V
t <sub>fr</sub>	Diode Forward Recovery Time	I <sub>F</sub> =0.4A	u		460		ns
-11	(di/dt=10A/µs)	I <sub>F</sub> =1A			360		ns
		I <sub>F</sub> =2A	1		325		ns
CE(DSAT)	Dynamic Saturation Voltage	I <sub>C</sub> =1A, I <sub>B1</sub> =100mA V <sub>CC</sub> =300V at 1 μs	T <sub>a</sub> =25°C		8		V
			T <sub>a</sub> =125°C		15		V
		$\label{eq:loss} \begin{array}{l} I_{C}{=}1A, \ I_{B1}{=}100mA \\ V_{CC}{=}300V \ at \ 3 \ \mu s \end{array} \\ \hline I_{C}{=}2A, \ I_{B1}{=}400mA \\ V_{CC}{=}300V \ at \ 1 \ \mu s \end{array}$	T <sub>a</sub> =25°C		2.9		V
			T <sub>a</sub> =125°C		8		V
			T <sub>a</sub> =25°C		9		V
			T <sub>a</sub> =125°C		17		V
		I <sub>C</sub> =2A, I <sub>B1</sub> =400mA	T <sub>a</sub> =25°C		1.9		V
		$V_{CC}$ =300V at 3 $\mu$ s	T <sub>a</sub> =125°C		8.5		V

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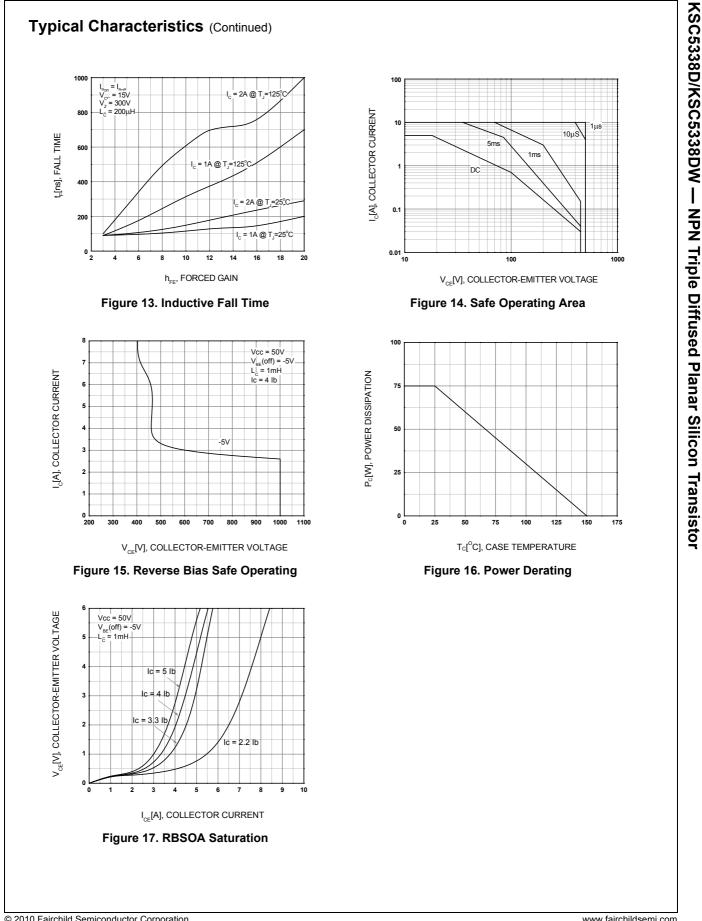
Symbol	Parameter	Test Co	ndition	Min	Тур.	Max.	Units
RESISTIVE	LOAD SWITCHING (D.C < 10%	, Pulse Width=40µs)					
t <sub>ON</sub>	Turn On Time	I <sub>C</sub> =2.5A, I <sub>B1</sub> =50	0mA,		500	750	ns
t <sub>STG</sub>	Storage Time	I <sub>B2</sub> =-1A, V <sub>CC</sub> =2	50V, R <sub>L</sub> = 100Ω	1.2		1.5	μS
t <sub>F</sub>	Fall Time		-		100	200	ns
t <sub>ON</sub>	Turn On Time	I <sub>C</sub> =2A,	T <sub>a</sub> =25°C		100	150	ns
011		I <sub>B1</sub> =400mA,	T <sub>a</sub> =125°C		150		ns
t <sub>STG</sub>	Storage Time	I <sub>B2</sub> =-1A,	T <sub>a</sub> =25°C		1.4	2.2	μS
010	, j	V <sub>CC</sub> =300V, R <sub>1</sub> = 150Ω	T <sub>a</sub> =125℃		1.7		μS
t⊨	Fall Time	1(1 = 10022	T <sub>a</sub> =25°C		90	150	ns
					150		ns
t <sub>ON</sub>	Turn On Time	I <sub>C</sub> =2.5A,	T <sub>a</sub> =25℃		120	150	ns
0N		I <sub>B1</sub> =500mA,			150		ns
t <sub>STG</sub>	Storage Time	I <sub>B2</sub> =-5mA,	T <sub>a</sub> =25℃	1.8		2.1	μS
-010		V <sub>CC</sub> =300V, R <sub>1</sub> = 120Ω	T <sub>a</sub> =125°C	-	2.6		μS
t <sub>F</sub>	Fall Time	K_ = 12002	T <sub>a</sub> =25°C		110	150	ns
		T <sub>a</sub> =125°C		160		ns	
NDUCTIVE	LOAD SWITCHING (V <sub>CC</sub> =15V)		·a · ·				
t <sub>STG</sub>	Storage Time	I <sub>C</sub> =2.5A,	T <sub>a</sub> =25°C		1.9	2.2	μS
-010		I <sub>B1</sub> =500mA,	T <sub>a</sub> =125°C		2.4		μS
t <sub>F</sub>	Fall Time	I <sub>B2</sub> =-0.5A,	T <sub>a</sub> =25°C		160	200	ns
т		V <sub>Z</sub> =350V, L <sub>C</sub> =300μH	T <sub>a</sub> =125°C		330		ns
t <sub>C</sub>	Cross-over Time	ι	T <sub>a</sub> =25°C		350	500	ns
-0			T <sub>a</sub> =125°C		750		ns
t <sub>STG</sub>	Storage Time	I <sub>C</sub> =2A,	T <sub>a</sub> =25°C	1.95		2.25	μS
-516		I <sub>B1</sub> =400mA,	T <sub>a</sub> =125°C		2.9	0	μS
t⊨	Fall Time	I <sub>B2</sub> =-0.4A,	T <sub>a</sub> =25°C		120	150	ns
۲		V <sub>Z</sub> =300V,	T <sub>a</sub> =125°C		270	100	ns
t <sub>C</sub>	Cross-over Time	L <sub>C</sub> =200μΗ	T <sub>a</sub> =25°C		300	450	ns
чС			T <sub>a</sub> =125℃		700	100	ns
t <sub>STG</sub>	Storage Time	I <sub>C</sub> =1A,	T <sub>a</sub> =125°C		0.6	0.8	μs
181G		I <sub>B1</sub> =100mA,	T <sub>a</sub> =23°C		1.0	0.0	μ3 μS
t⊨	Fall Time	I <sub>B2</sub> =-0.5A,	$T_a=125^{\circ}C$ $T_a=25^{\circ}C$		70		ns
4		V <sub>Z</sub> =300V,	T <sub>a</sub> =25 ℃ T <sub>a</sub> =125°C		110		ns
t <sub>C</sub>	Cross-over Time	L <sub>C</sub> =200μΗ	$T_a=125^{\circ}C$ $T_a=25^{\circ}C$		80	130	ns
۲C			T <sub>a</sub> =23 °C T <sub>a</sub> =125°C		170	100	ns



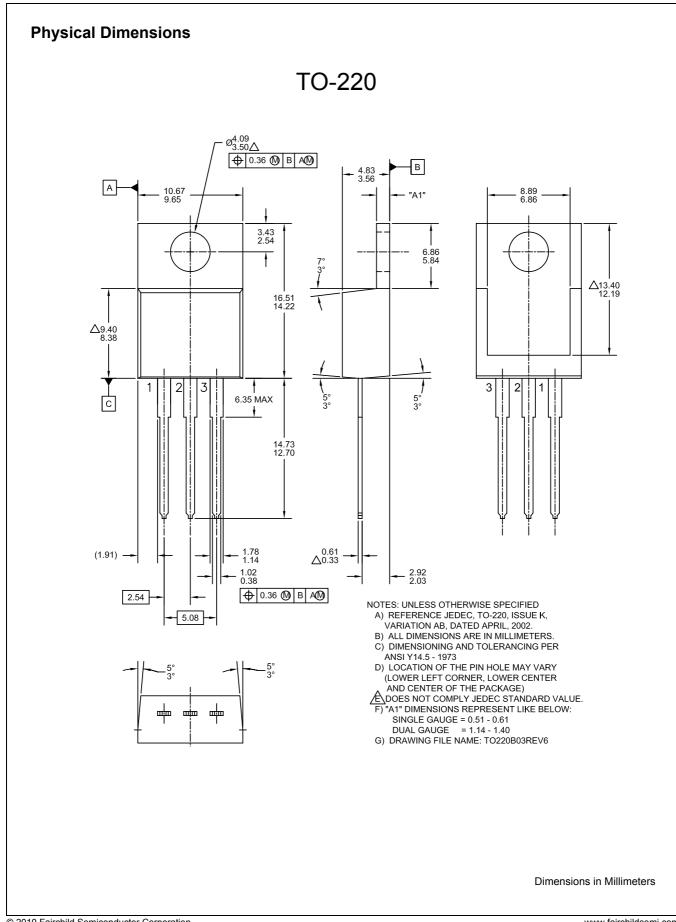


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